

# 2SB1722JOL Datasheet



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DiGi Electronics Part Number 2SB1722J0L-DG

Manufacturer Panasonic Electronic Components

Manufacturer Product Number 2SB1722J0L

Description TRANS PNP 100V 0.02A SSMINI3

**Detailed Description** Bipolar (BJT) Transistor PNP 100 V 20 mA 200MHz 1

25 mW Surface Mount SSMini3-F1



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DiGi is a global authorized distributor of electronic components.



## **Purchase and inquiry**

| Manufacturer Product Number:                 | Manufacturer:                          |
|--|--|
| 2SB1722J0L                                   | Panasonic Electronic Components        |
| Series:                                      | Product Status:                        |
|  | Obsolete                               |
| Transistor Type:                             | Current - Collector (Ic) (Max):        |
| PNP  | 20 mA                                  |
| Voltage - Collector Emitter Breakdown (Max): | Vce Saturation (Max) @ lb, Ic:         |
| 100 V  | 300mV @ 1mA, 10mA                      |
| Current - Collector Cutoff (Max):            | DC Current Gain (hFE) (Min) @ lc, Vce: |
| 1μΑ  | 200 @ 2mA, 10V                         |
| Power - Max:                                 | Frequency - Transition:                |
| 125 mW                                       | 200MHz                                 |
| Operating Temperature:                       | Mounting Type:                         |
| 125°C (TJ)                                   | Surface Mount                          |
| Package / Case:                              | Supplier Device Package:               |
| SC-89, SOT-490                               | SSMini3-F1                             |
| Base Product Number:                         |  |
| 2SB1722                                      |  |

## **Environmental & Export classification**

| Moisture Sensitivity Level (MSL): | ECCN: |
|-----------------------------------|-------|
| 1 (Unlimited)                     | EAR99 |
| HTSUS:                            |       |
| 8541.21.0075                      |       |

# 2SB1722J

### Silicon PNP epitaxial planar type

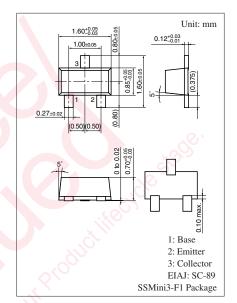
For high breakdown voltage low-frequency amplification

#### ■ Features

- ullet High collector-emitter voltage (Base open)  $V_{CEO}$
- SS-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing

#### ■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter                             | Symbol           | Rating      | Unit |  |
|---------------------------------------|------------------|-------------|------|--|
| Collector-base voltage (Emitter open) | $V_{CBO}$        | -100        | V    |  |
| Collector-emitter voltage (Base open) | $V_{CEO}$        | -100        | V    |  |
| Emitter-base voltage (Collector open) | V <sub>EBO</sub> | -5          | V    |  |
| Collector current                     | $I_{C}$          | -20         | mA   |  |
| Peak collector current                | $I_{CP}$         | -50         | mA   |  |
| Collector power dissipation           | P <sub>C</sub>   | 125         | mW   |  |
| Junction temperature                  | $T_{j}$          | 125         | °C   |  |
| Storage temperature                   | T <sub>stg</sub> | -55 to +125 | °C   |  |



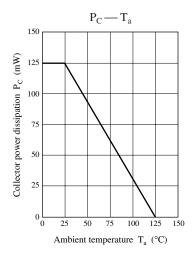
Marking Symbol: 4R

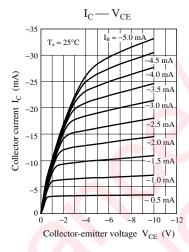
#### ■ Electrical Characteristics T<sub>a</sub> = 25°C ± 3°C

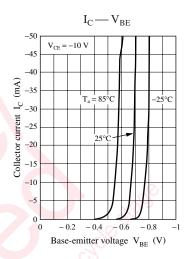
| Parameter                                     | Symbol               | Conditions   | Min  | Тур | Max   | Unit |
|---|----------------------|--|------|-----|-------|------|
| Collector-base voltage (Emitter open)         | $V_{CBO}$            | $I_{\rm C} = -10 \; \mu \text{A}, \; I_{\rm E} = 0$              | -100 |     |       | V    |
| Collector-emitter voltage (Base open)         | V <sub>CEO</sub>     | $I_{\rm C} = -1 \text{ mA}, I_{\rm B} = 0$                       | -100 |     |       | V    |
| Emitter-base voltage (Collector open)         | $V_{EBO}$            | $I_E = -10 \mu\text{A}, I_C = 0$                                 | -5   |     |       | V    |
| Collector-base cutoff current (Emitter open)  | $I_{CBO}$            | $V_{CB} = -50 \text{ V}, I_E = 0$                                |      |     | -100  | nA   |
| Collector-emitter cut-off current (Base open) | $I_{CEO}$            | $V_{CE} = -50 \text{ V}, I_{B} = 0$                              |      |     | -1    | μΑ   |
| Forward current transfer ratio                | h <sub>FE</sub>      | $V_{CE} = -10 \text{ V}, I_{C} = -2 \text{ mA}$                  | 200  |     | 700   | _    |
| Collector-emitter saturation voltage          | V <sub>CE(sat)</sub> | $I_C = -10 \text{ mA}, I_B = -1 \text{ mA}$                      |      |     | - 0.3 | V    |
| Transition frequency                          | $f_T$                | $V_{CB} = -5 \text{ V}, I_E = 2 \text{ mA}, f = 200 \text{ MHz}$ |      | 200 |       | MHz  |

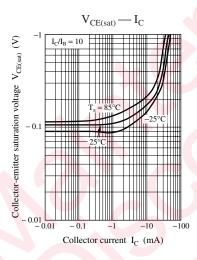
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

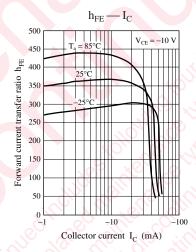
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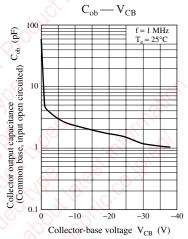












2 SJC00305AED

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